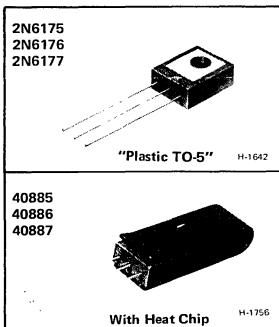




Power Transistors

2N6175 40885
2N6176 40886
2N6177 40887



High-Voltage, Medium-Power Silicon N-P-N Transistors

For High-Speed Switching and Linear-Amplifier Applications

Features

- Thermal fatigue ratings
- High frequency response: $f_T = 20$ MHz
- Maximum area-of-operation curves for DC and pulse operation
- Designed to assure freedom from second breakdown in class A, B, and C operation at maximum ratings

RCA types 2N6175, 2N6176, and 2N6177* are silicon n-p-n transistors with high breakdown voltages, high frequency response, and fast switching speeds. Types 40885, 40886, and 40887 are electrically identical to the 2N6175–2N6177, respectively, but are supplied with factory-attached heat clips.

Typical applications for these devices include TV video output, RGB output, chroma output, TV blanking, solenoid drivers, off-line inverters, regulators, audio output, and electrostatic deflection in display circuits.

*Formerly Dev. Nos. TA7739, TA7740 and TA7134, respectively.

MAXIMUM RATINGS, Absolute-Maximum Values:

| | 2N6175 | 2N6176 | 2N6177 | |
|---|--------------------------|--------|--------|-----|
| *COLLECTOR-TO-BASE VOLTAGE | 40885 | 40886 | 40887 | V |
| *COLLECTOR-TO-EMITTER SUSTAINING VOLTAGE | $V_{CEO(sus)}$ | 300 | 350 | 450 |
| *EMITTER-TO-BASE VOLTAGE | V_{EBO} | 250 | 300 | 350 |
| *COLLECTOR CURRENT | I_C | 6 | 6 | 6 |
| *BASE CURRENT | I_B | 1.0 | 1.0 | 1.0 |
| *TRANSISTOR DISSIPATION | P_T | 0.5 | 0.5 | 0.5 |
| At case temperatures up to 25°C | 20 | 20 | 20 | W |
| At case temperatures above 25°C | (2N6175, 2N6176, 2N6177) | | | |
| At ambient temperatures up to 25°C | See Fig. 14 | | | |
| At ambient temperatures above 25°C | 0.8 | 0.8 | 0.8 | W |
| For pulse operation | (2N6175, 2N6176, 2N6177) | | | |
| *TEMPERATURE RANGE: | 1.4 | 1.4 | 1.4 | W |
| Storage & Operating (Junction) | (40885, 40886, 40887) | | | |
| *LEAD TEMPERATURE (During soldering): | See Fig. 15 | | | |
| At distance $\geq 1/16$ in. (1.59 mm) from case for 10 s max. | See Figs. 1, 4, and 7 | | | |

*Types 2N6175, 2N6176, and 2N6177 in accordance with JEDEC registration data format JS-9 RFD-8.

ELECTRICAL CHARACTERISTICS, At Case Temperature ($T_C = 25^\circ C$)

| CHARACTERISTIC | SYMBOL | TEST CONDITIONS | | | | LIMITS | | | | | | UNITS | |
|--|-------------------------------|----------------------|--|--|------------------|--------------------|---------------------------------|--------------------|--------------------|---------------------------------|--------------------|-------|--|
| | | VOLTAGE V dc | | CUR- RENT mA dc | 2N6175 40885 | | 2N6176 40886 | | 2N6177 40887 | | | | |
| | | V _{CB} | V _{CE} | I _C | I _B | MIN. | MAX. | MIN. | MAX. | MIN. | MAX. | | |
| Collector-Cutoff Current: With base open | I _{CEO} | | 300 200 | 0 0 | — — | — 50 | — — | — 50 | — — | — 20 | — — | μA | |
| * With emitter open | I _{CBO} | 360 280 240 | | | — — — | — — 50 | — — | — 50 | — — | — 20 | — — | | |
| With base-emitter junction reverse-biased, V _{BE} = -1.5 V | I _{CEV} | | 450 300 | | — — | — 500 | — — | — 500 | — — | — 500 | — — | | |
| * Emitter-Cutoff Current, V _{BE} = -6 V | I _{EBO} | | | 0 | — | 20 | — | 20 | — | 20 | — | μA | |
| DC Forward-Current Transfer Ratio | h _{FE} | 10 10 10 10 | 50 ^a 20 ^a 5 ^a 1 ^a | 50 ^a 30 ^a 15 | — — — — | — 190 — — | — 30 ^a 15 — | — 150 — — | — 150 — — | 30 ^a — 15 — | 150 — — — | | |
| Collector-to-Emitter Sustaining Voltage: With base open | V _{CEO(sus)} | | | 50 ^a | 0 | 250 ^b | — | 300 ^b | — | 350 ^b | — | V | |
| Base-to-Emitter Saturation Voltage | V _{BE(sat)} | | | 50 ^a | 4 | — | 1.3 | — | 1.3 | — | 1.3 | V | |
| Collector-to-Emitter Saturation Voltage | V _{CE(sat)} | | | 50 ^a | 4 | — | 0.5 | — | 0.5 | — | 0.5 | V | |
| * Collector-to-Base Breakdown Voltage | V _{(BR)CBO} | | | 1 ^a | — | 300 | — | 350 | — | 450 | — | V | |
| * Low-Frequency, Common-Emitter, Small-Signal, Short-Circuit, Forward-Current Transfer Ratio f = 1 kHz | h _{fe} | 10 | 5 | — | 25 | — | 25 | — | 25 | — | 25 | — | |
| * Magnitude of Common-Emitter, Small-Signal, Short-Circuit, Forward-Current Transfer Ratio f = 3 MHz | h _{fe} | 20 | 20 | — | 7 | — | 7 | — | 7 | — | 7 | — | |
| * Real Part of Common-Emitter, Small-Signal, Short-Circuit Input Impedance: f = 1 MHz | Re(h _{ie}) | 10 | 20 5 | — — | 300 — | — — | — 300 | — — | — — | — 300 | — — | Ω | |
| * Output Capacitance: f = 1 MHz | C _{cb} | 20 | | — | 8 | — | 8 | — | 8 | — | 8 | pF | |
| Second-Breakdown Collector Current: With base forward biased, t = 0.4 s nonrepetitive | I _{S/b} ^b | 150 | | 133 | — | 133 | — | 133 | — | 133 | — | mA | |
| Thermal Resistance: Junction-to-Case | R _{θJC} | | | — | 5.5 (2N6175) | — | 5.5 (2N6176) | — | 5.5 (2N6177) | — | 5.5 (2N6177) | | |
| Junction-to-Ambient | R _{θJA} | | | — | 138 (2N6175) | — | 138 (2N6176) | — | 138 (2N6177) | — | 138 (2N6177) | °C/W | |

^a Types 2N6175, 2N6176, and 2N6177 in accordance with JEDEC registration data format JS-9 RDF-8.^aPulsed Pulse duration = 300 μs; duty factor $\leq 2\%$.^bCAUTION: The sustaining voltage V_{CEO(sus)} MUST NOT be measured on a curve tracer. The sustaining voltage should be measured by means of the test circuit shown in Fig. 10

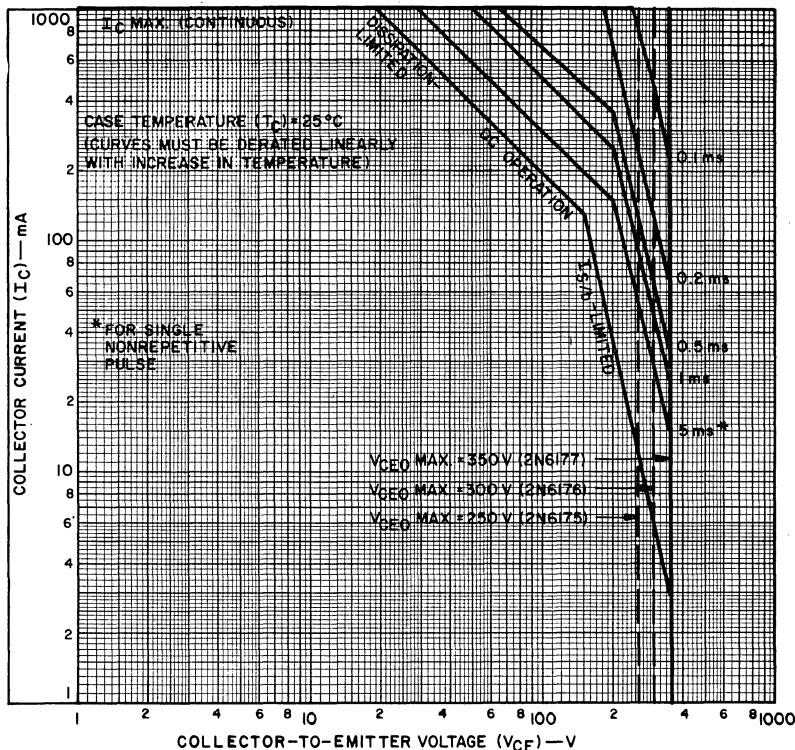


Fig. 1—Maximum safe-operation-areas for types 2N6175, 2N6176, and 2N6177.

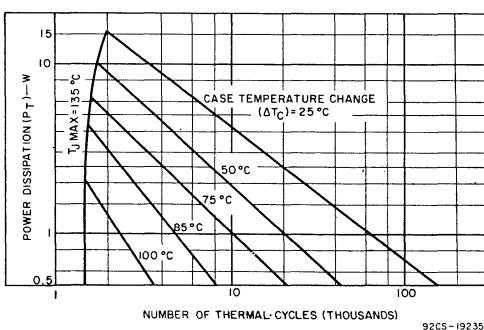


Fig. 2—Thermal-cycling rating chart.

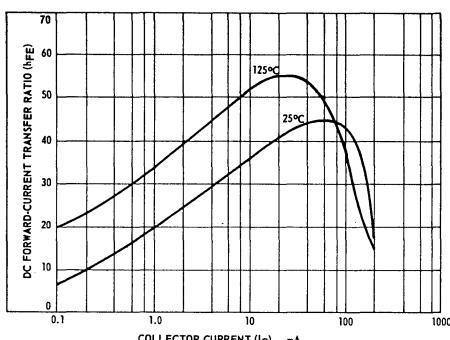


Fig. 3—Typical DC-beta characteristics for all types.

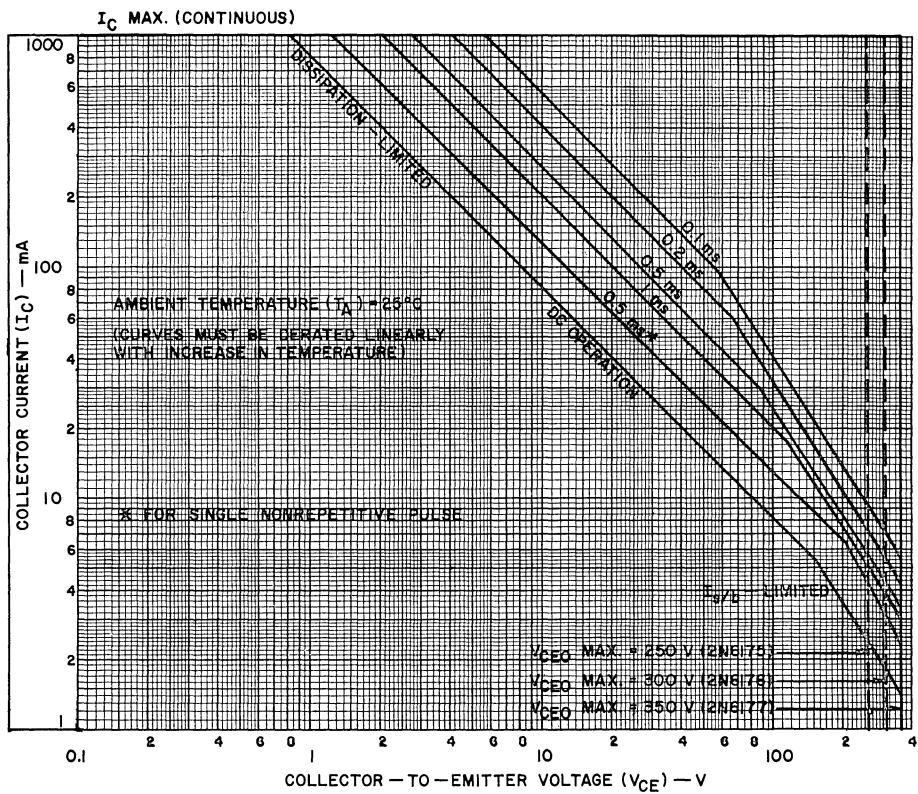


Fig. 4—Maximum safe area-of-operation at ambient temperature
for types 2N6175, 2N6176, and 2N6177.

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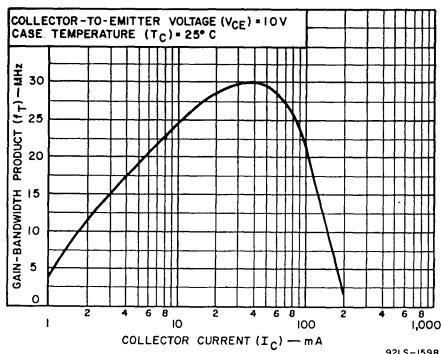


Fig. 5—Typical gain-bandwidth product for all types.

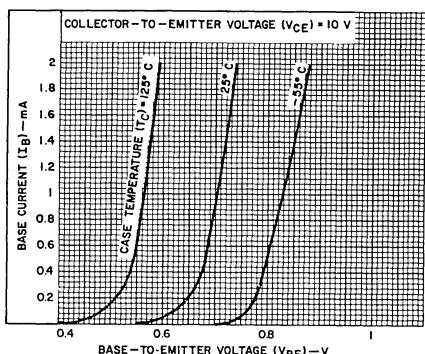


Fig. 6—Typical input characteristics for all types.

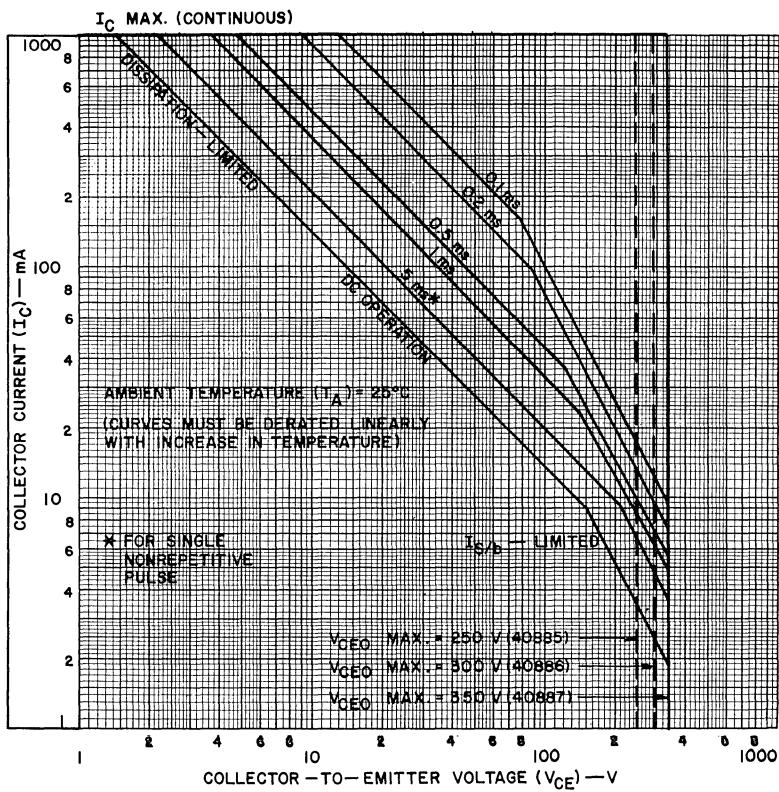


Fig.7—Maximum safe area-of-operation for types 40885, 40886, and 40887.

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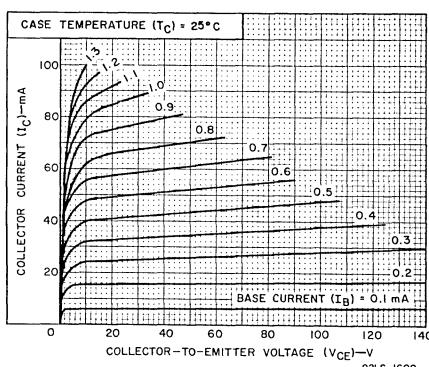


Fig. 8—Typical output characteristics for all types.

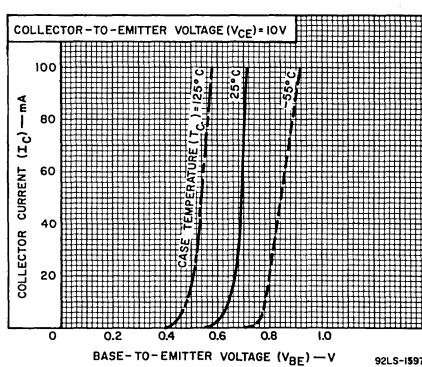


Fig. 9—Typical transfer characteristics for all types.

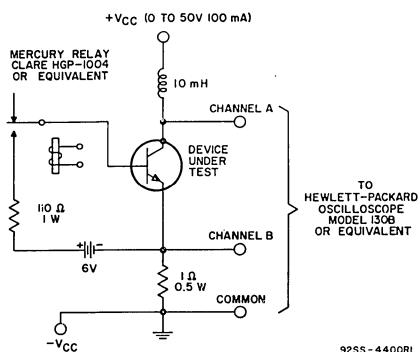
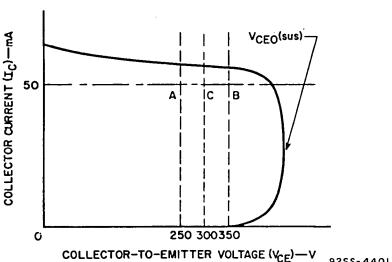


Fig.10—Circuit used to measure sustaining voltage, $V_{CEO(sus)}$.



The sustaining voltage $V_{CEO(sus)}$ is acceptable when the trace falls to the right and above point "A" for type 2N6175 or 40885. The trace must fall to the right and above point "B" for type 2N6177 or 40887 and above and to the right of point "C" for type 2N6176 or 40886.

Fig.11—Oscilloscope display for measurement of sustaining voltages (test circuit shown in Fig. 9).

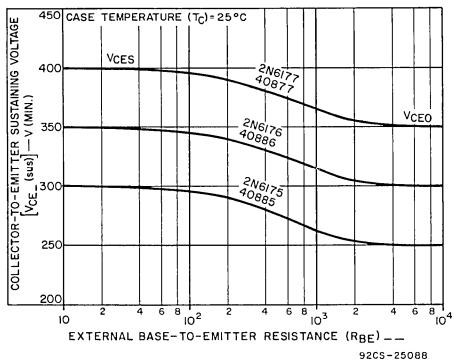


Fig. 12—Sustaining voltage vs. base-to-emitter resistance for all types.

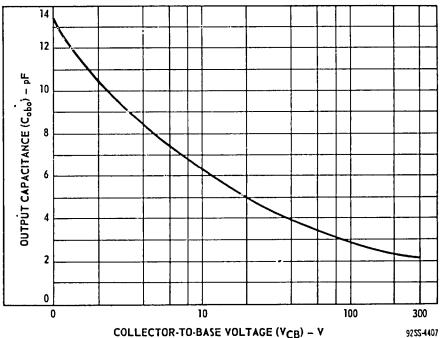


Fig.13—Typical output capacitance vs collector-to-base voltage for all types.

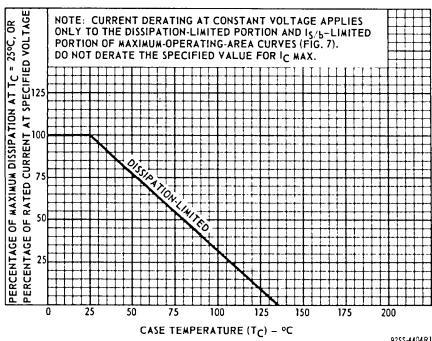


Fig.14—Dissipation derating curve for all types.

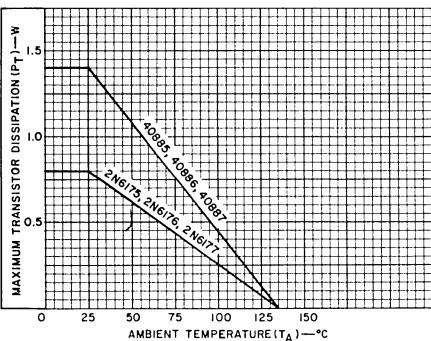


Fig.15—Dissipation derating curves for all types.